

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	(semiconductor and substrate and (insulat\$3 near2 (film layer)) and (plurality near2 cycle) and purg\$3 and supply\$3 and oxidant and (gate near2 electrode)).clm.	US-PGPUB	OR	ON	2006/05/18 21:04

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L6	905	(438/287).CCLS.	US-PGPUB; USPAT	OR	OFF	2006/05/18 17:26
L7	104	6 and (@pd>="20051001")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/18 17:29
L8	394	(438/216).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/18 17:29
L9	57	8 and (@pd>="20051001")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/18 17:32
L10	620	(438/591).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/18 17:32
L11	57	10 and (@pd>="20051001")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/18 17:34
L12	772	(438/785).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/18 17:34
L13	91	12 and (@pd>="20051001")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/18 17:37

## EAST Search History

L14	779	(438/685).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/18 17:37
L15	37	14 and (@pd>="20051001")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/18 17:51
L16	157	(438/679).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/18 17:51
L17	9	16 and (@pd>="20051001")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/18 17:53
L18	1713	(438/680).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/18 17:53
L19	61	18 and (@pd>="20051001")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/18 17:54